
2SK2529

Silicon N-Channel MOS FET

HITACHI

ADE-208-356F
7th. Edition

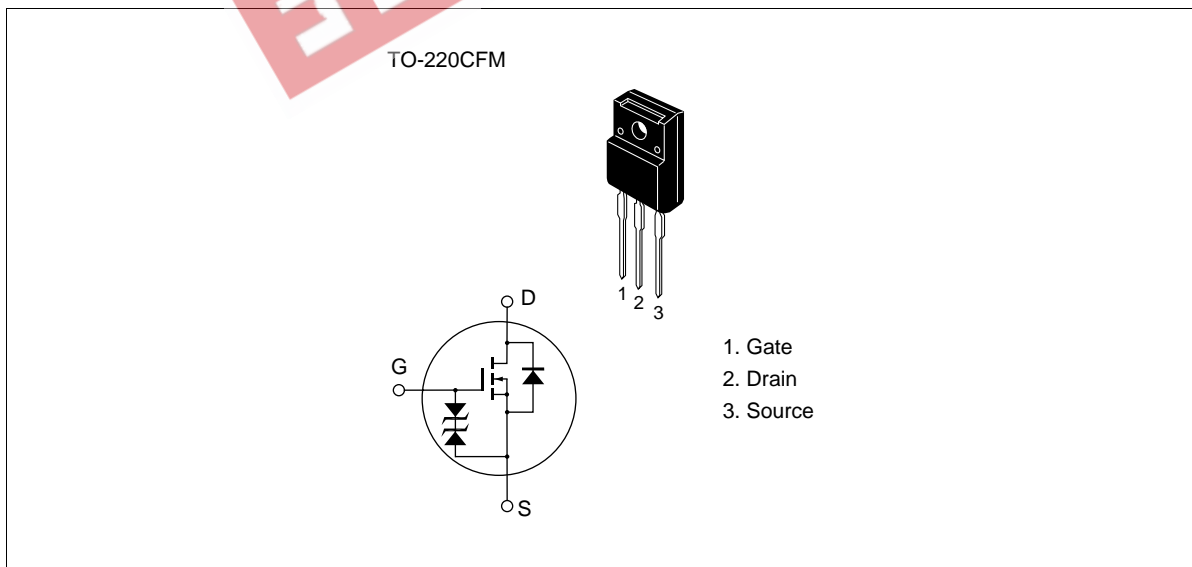
Application

High speed power switching

Features

- Low on-resistance
- $R_{DS(on)} = 7 \text{ m}\Omega$ typ.
- High speed switching
- 4 V gate drive device can be driven from 5 V source

Outline



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Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Ratings	Unit
Drain to source voltage	V_{DSS}	60	V
Gate to source voltage	V_{GSS}	±20	V
Drain current	I_D	50	A
Drain peak current	$I_{D(pulse)}^{*1}$	200	A
Body to drain diode reverse drain current	I_{DR}	50	A
Avalanche current	I_{AP}^{*3}	45	A
Avalanche energy	E_{AR}^{*3}	174	mJ
Channel dissipation	Pch^{*2}	35	W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

- Notes
1. $PW \leq 10 \mu s$, duty cycle $\leq 1 \%$
 2. Value at $Tc = 25^\circ C$
 3. Value at $Tch = 25^\circ C$, $Rg \geq 50 \Omega$

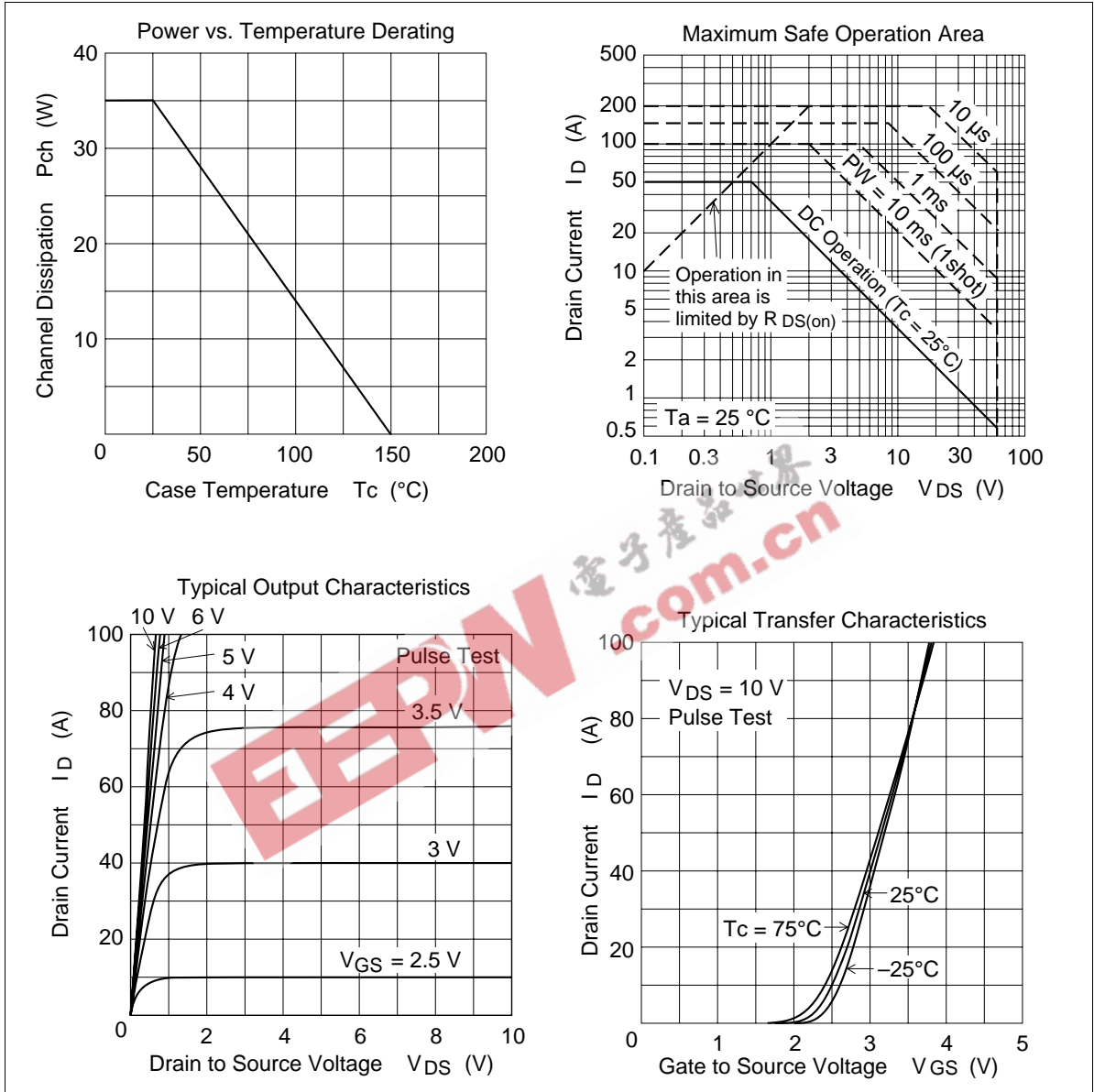
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Electrical Characteristics (T_a = 25°C)

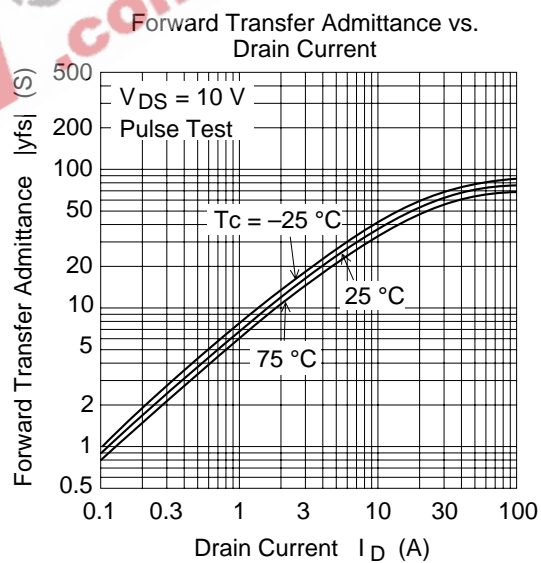
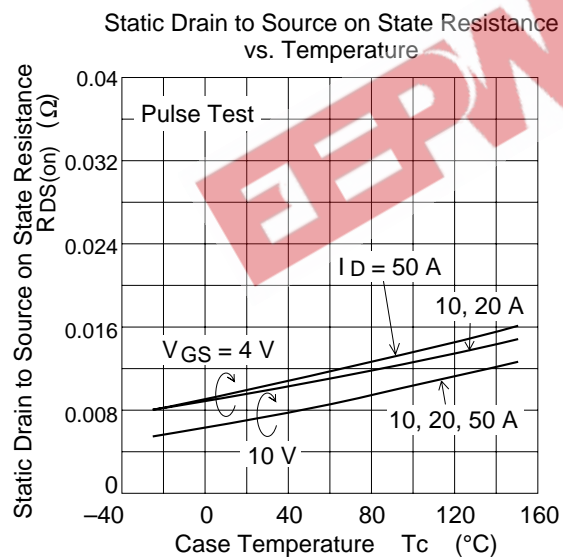
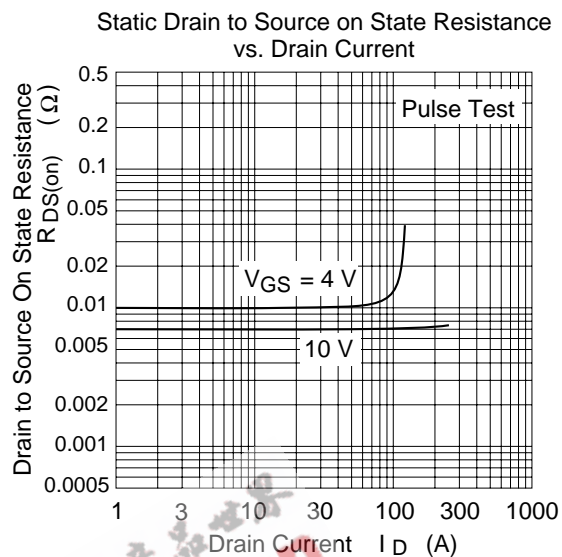
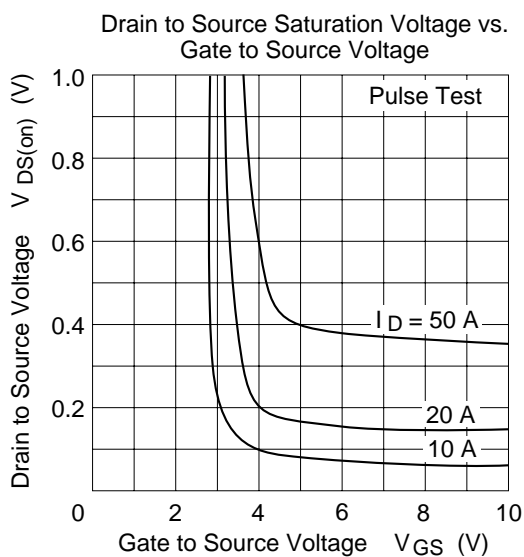
Item	Symbol	Min	Typ	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	60	—	—	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source breakdown voltage	$V_{(BR)GSS}$	±20	—	—	V	$I_G = \pm 100 \text{ } \mu\text{A}, V_{DS} = 0$
Gate to source leak current	I_{GSS}	—	—	±10	μA	$V_{GS} = \pm 16 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I_{DSS}	—	—	10	μA	$V_{DS} = 60 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.0	—	2.0	V	$I_D = 1 \text{ mA}, V_{DS} = 10 \text{ V}$
Static drain to source on state resistance	$R_{DS(on)}$	—	7	10	mΩ	$I_D = 25 \text{ A}$ $V_{GS} = 10 \text{ V}^{*1}$
		—	10	16	mΩ	$I_D = 25 \text{ A}$ $V_{GS} = 4 \text{ V}^{*1}$
Forward transfer admittance	$ y_{fs} $	35	55	—	S	$I_D = 25 \text{ A}$ $V_{DS} = 10 \text{ V}^{*1}$
Input capacitance	C_{iss}	—	3550	—	pF	$V_{DS} = 10 \text{ V}$
Output capacitance	C_{oss}	—	1760	—	pF	$V_{GS} = 0$
Reverse transfer capacitance	C_{rss}	—	500	—	pF	$f = 1 \text{ MHz}$
Turn-on delay time	$t_{d(on)}$	—	35	—	ns	$I_D = 25 \text{ A}$
Rise time	t_r	—	230	—	ns	$V_{GS} = 10 \text{ V}$
Turn-off delay time	$t_{d(off)}$	—	470	—	ns	$R_L = 1.2 \text{ } \Omega$
Fall time	t_f	—	360	—	ns	
Body to drain diode forward voltage	V_{DF}	—	0.85	—	V	$I_F = 50 \text{ A}, V_{GS} = 0$
Body to drain diode reverse recovery time	t_{rr}	—	135	—	ns	$I_F = 50 \text{ A}, V_{GS} = 0$ $di_F / dt = 50 \text{ A} / \mu\text{s}$

Note 1. Pulse Test

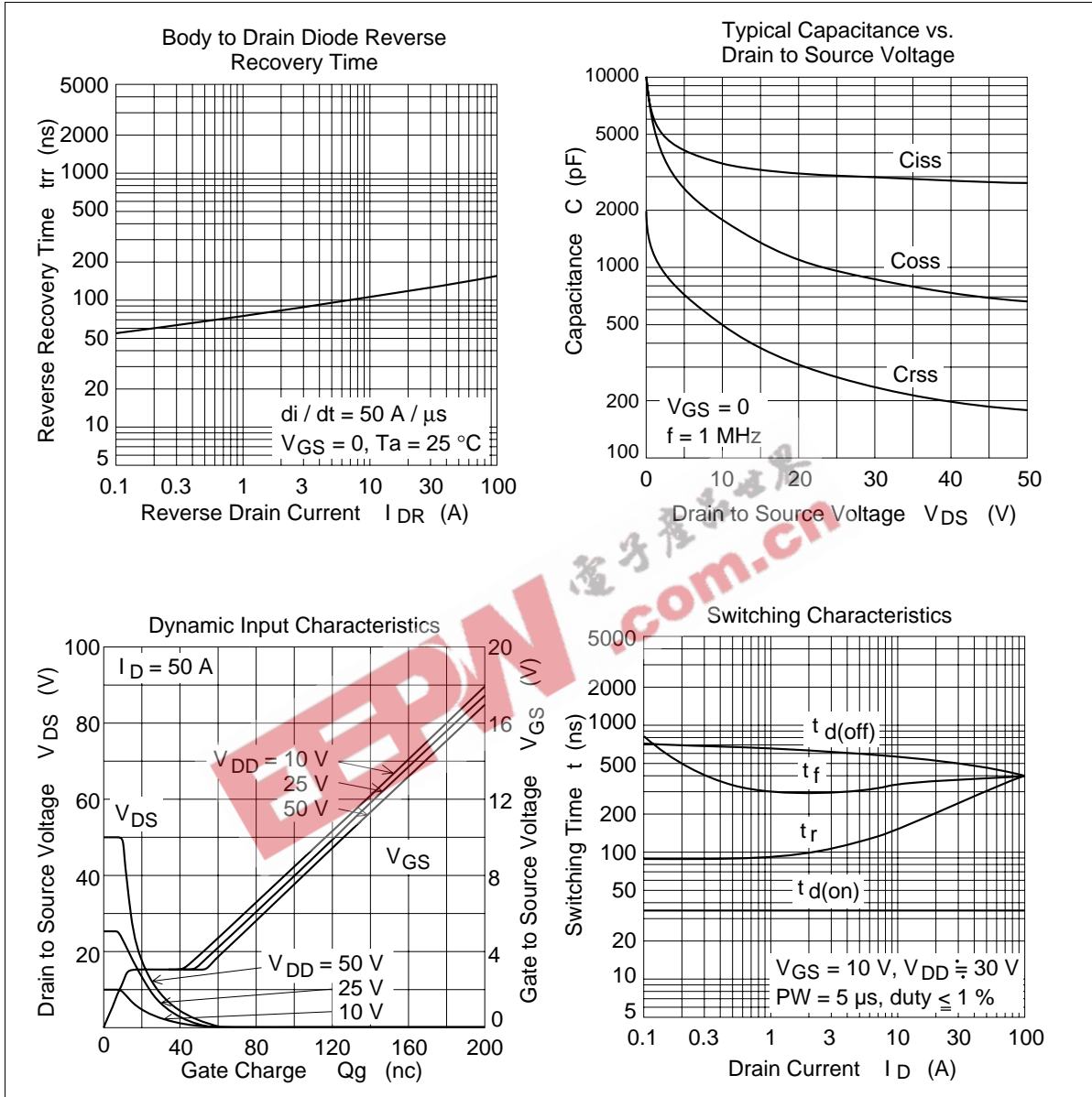
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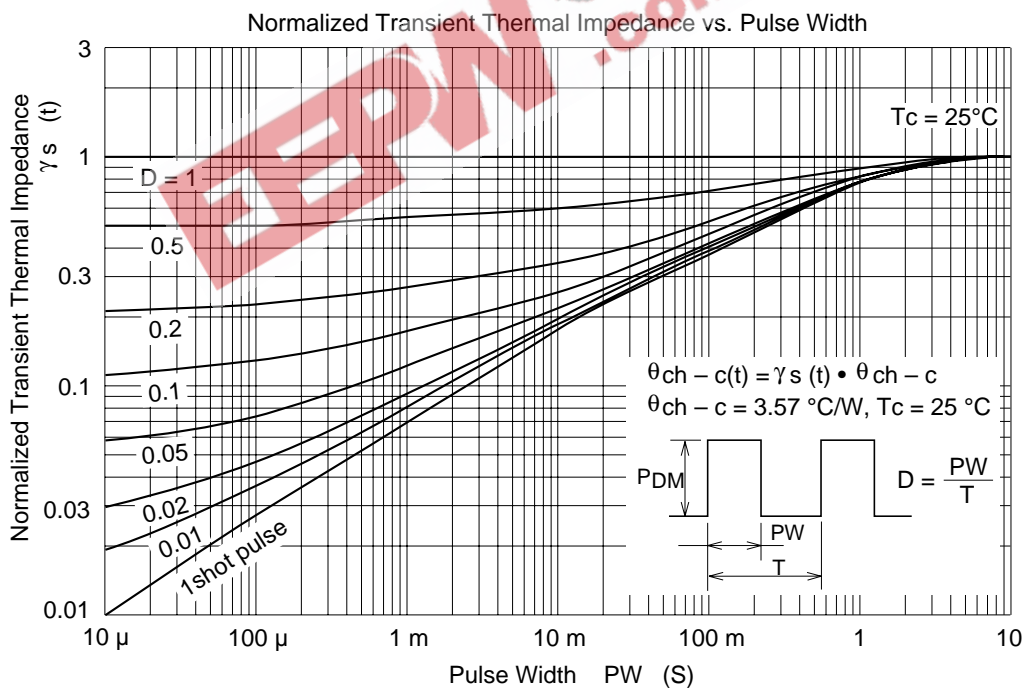
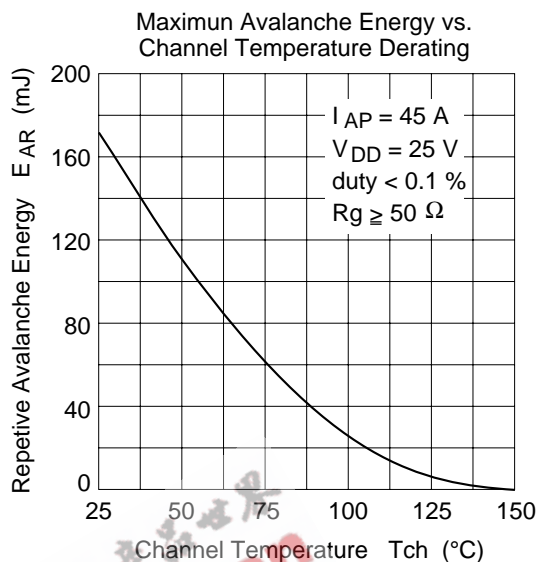
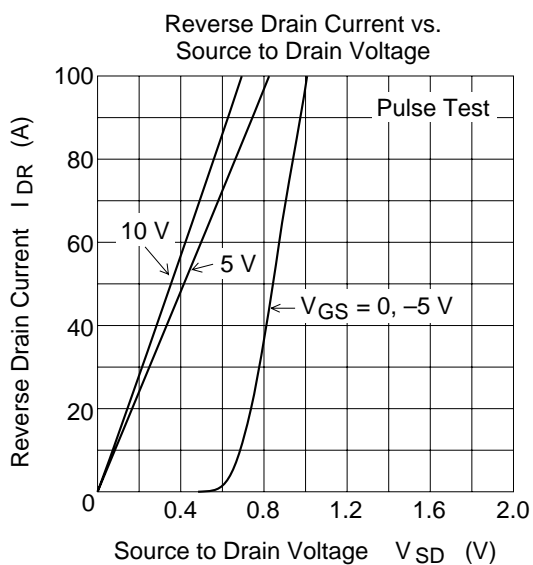


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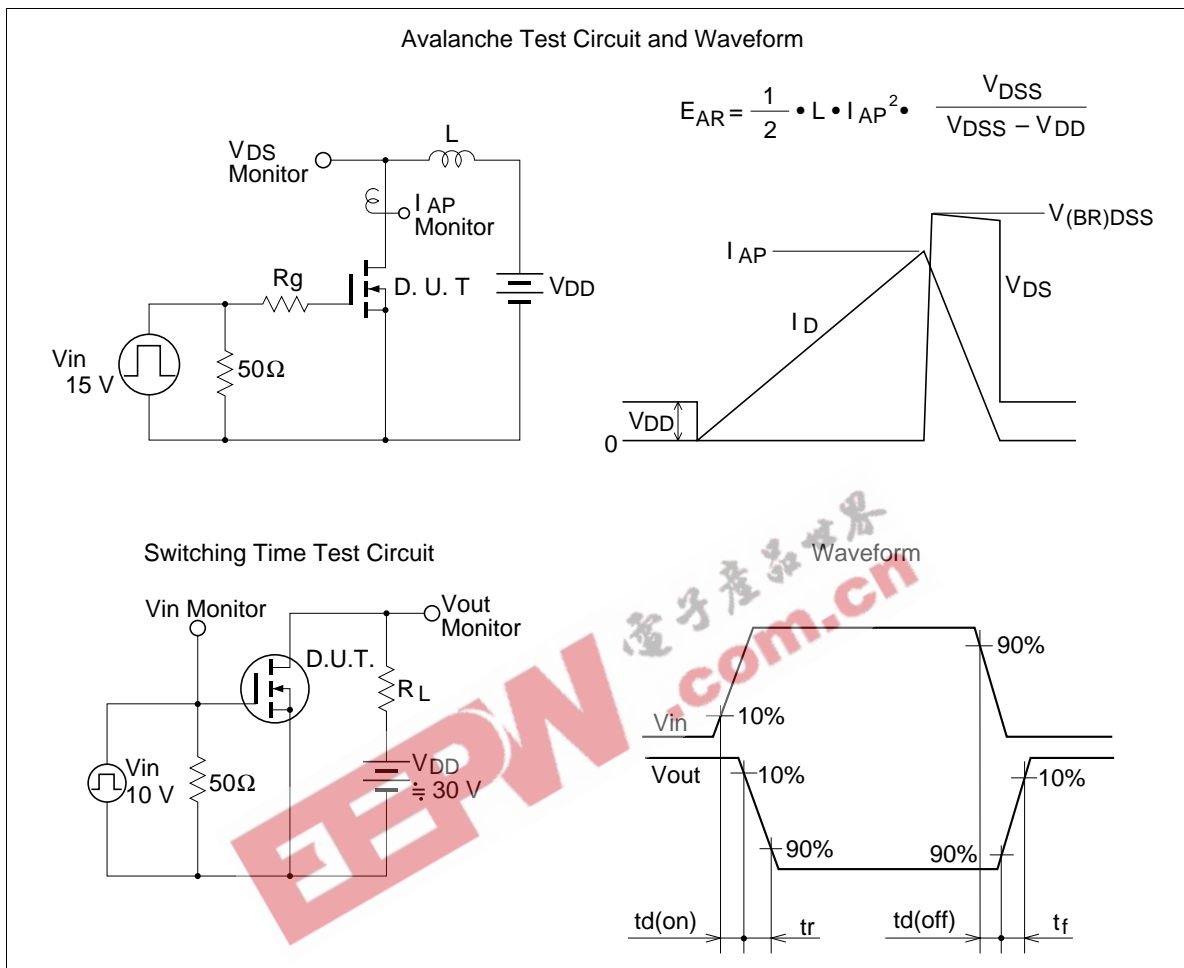


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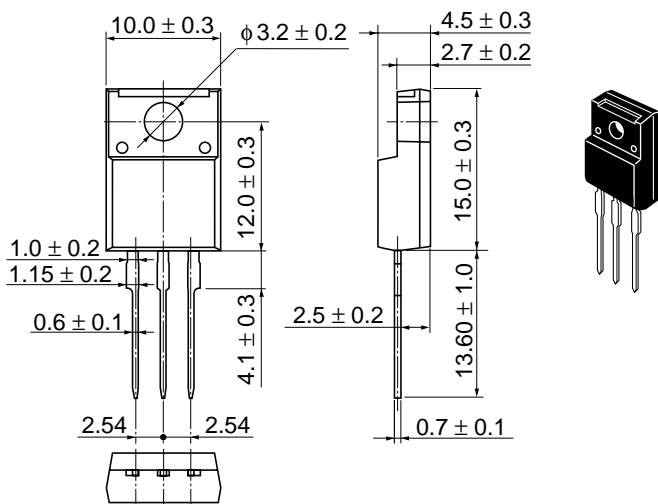




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Unit: mm



Hitachi Code	TO-220CFM
JEDEC	—
EIAJ	—
Weight (reference value)	1.9 g

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